

TLV27L1
TLV27L2

SLOS378A – SEPTEMBER 2001 – REVISED JULY 2003

FAMILY OF MICROPOWER RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS

FEATURES

- BiMOS Rail-to-Rail Output
- Input Bias Current . . . 1 pA
- High Wide Bandwidth . . . 160 kHz
- High Slew Rate . . . 0.1 V/ μ s
- Supply Current . . . 7 μ A (per channel)
- Input Noise Voltage . . . 89 nV/ $\sqrt{\text{Hz}}$
- Supply Voltage Range . . . 2.7 V to 16 V
- Specified Temperature Range
 - -40°C to 125°C . . . Industrial Grade
 - 0°C to 70°C . . . Commercial Grade
- Ultra-Small Packaging
 - 5 Pin SOT-23 (TLV27L1)

APPLICATIONS

- Portable Medical
- Power Monitoring
- Low Power Security Detection Systems
- Smoke Detectors

DESCRIPTION

The TLV27Lx single supply operational amplifiers provide rail-to-rail output capability. The TLV27Lx takes the minimum operating supply voltage down to 2.7 V over the extended industrial temperature range, while adding the rail-to-rail output swing feature. The TLV27Lx also provides 160-kHz bandwidth from only 7 μ A. The maximum recommended supply voltage is 16 V, which allows the devices to be operated from (± 8 -V supplies down to ± 1.35 V) two rechargeable cells.

The rail-to-rail outputs make the TLV27Lx good upgrades for the TLC27Lx family—offering more bandwidth at a lower quiescent current. The TLV27Lx offset voltage is equal to that of the TLC27LxA variant. Their cost effectiveness makes them a good alternative to the TLC/V225x, where offset and noise are not of premium importance.

The TLV27L1/2 are available in the commercial temperature range to enable easy migration from the equivalent TLC27Lx. The TLV27L1 is not available with the power saving/performance boosting programmable pin 8.

The TLV27L1 is available in the small SOT-23 package—something the TLC27(L)1 was not—enabling performance boosting in a smaller package. The TLV27L2 is available in the 3mm x 5mm MSOP, providing PCB area savings over the 8-pin SOIC and 8-pin TSSOP.

SELECTION GUIDE

DEVICE	V _S [V]	I _Q /ch [μ A]	V _{ICR} [V]	V _{IO} [mV]	I _{IB} [pA]	GBW [MHz]	SLEW RATE [V/ μ s]	V _n , 1 kHz [nV/ $\sqrt{\text{Hz}}$]
TLV27Lx	2.7 to 16	11	-0.2 to $V_S+1.2$	5	60	0.18	0.06	89
TLV238x	2.7 to 16	10	-0.2 to $V_S-0.2$	4.5	60	0.18	0.06	90
TLC27Lx	4 to 16	17	-0.2 to $V_S-1.5$	10/5/2	60	0.085	0.03	68
OPAx349	1.8 to 5.5	2	-0.2 to $V_S+0.2$	10	10	0.070	0.02	300
OPAx347	2.3 to 5.5	34	-0.2 to $V_S+0.2$	6	10	0.35	0.01	60
TLC225x	2.7 to 16	62.5	0 to $V_S-1.5$	1.5/0.85	60	0.200	0.02	19

NOTE: All dc specs are maximums while ac specs are typicals.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



Copyright © 2001–2003, Texas Instruments Incorporated

TLV27L1 TLV27L2

SLOS378A – SEPTEMBER 2001 – REVISED JULY 2003

PACKAGE/ORDERING INFORMATION

PRODUCT	PACKAGE	PACKAGE CODE	SYMBOL	SPECIFIED TEMPERATURE RANGE	ORDER NUMBER	TRANSPORT MEDIA
TLV27L1CD	SOIC-8	D	27V1C	0°C to 70°C	TLV27L1CD	Tube
					TLV27L1CDR	Tape and Reel
TLV27L1CDBV	SOT-23	DBV	VBIC		TLV27L1CDBVR	Tape and Reel
					TLV27L1CDBVT	
TLV27L1ID	SOIC-8	D	27V1I	−40°C to 125°C	TLV27L1ID	Tube
					TLV27L1IDR	Tape and Reel
TLV27L1IDBV	SOT-23	DBV	VBII		TLV27L1IDBVR	Tape and Reel
					TLV27L1IDBVT	
TLV27L2CD	SOIC-8	D	27V2C	0°C to 70°C	TLV27L2CD	Tube
					TLV27L2CDR	Tape and Reel
TLV27L2ID	SOIC-8	D	27V2I	−40°C to 125°C	TLV27L2ID	Tube
					TLV27L2IDR	Tape and Reel

absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage, V_S	16.5 V
Input voltage, V_I (see Note 1)	V_S
Output current, I_O	100 mA
Differential input voltage, V_{ID}	V_S
Continuous total power dissipation	See Dissipation Rating Table
Maximum junction temperature, T_J	150°C
Operating free-air temperature range, T_A : C suffix	0°C to 70°C
I suffix	–40°C to 125°C
Storage temperature range, T_{stg}	–65°C to 125°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	300°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: Relative to GND pin.

DISSIPATION RATING TABLE

PACKAGE	θ_{JC} (°C/W)	θ_{JA} (°C/W)	$T_A \leq 25^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
D (8)	38.3	176	710 mW	370 mW
DBV (5)	55	324.1	385 mW	201 mW
DBV (6)	55	294.3	425 mW	221 mW

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, (V_S)	Dual supply	±1.35	±8	V
	Single supply	2.7	16	
Input common-mode voltage range		–0.2	$V_S - 1.2$	V
Operating free-air temperature, T_A	C-suffix	0	70	°C
	I-suffix	–40	125	

electrical characteristics at recommended operating conditions, $V_S = 2.7\text{ V}$, 5 V , and 10 V (unless otherwise noted)

dc performance

PARAMETER	TEST CONDITIONS	T_A^\dagger	MIN	TYP	MAX	UNIT
V_{IO} Input offset voltage	$V_{IC} = V_S/2$, $R_L = 100\text{ k}\Omega$, $V_O = V_S/2$, $R_S = 50\text{ }\Omega$	25°C		0.5	5	mV
		Full range			7	
α_{VIO} Offset voltage drift		25°C		1.1		$\mu\text{V}/^\circ\text{C}$
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ V to }V_S - 1.2\text{ V}$, $R_S = 50\text{ }\Omega$	25°C	71	86		dB
		Full range	70			
A_{VD} Large-signal differential voltage amplification	$V_{O(PP)} = V_S/2$, $R_L = 100\text{ k}\Omega$	$V_S = 2.7\text{ V}$, 5 V	25°C	80	100	dB
		Full range		77		
	$V_S = \pm 5\text{ V}$	25°C	77	82		
		Full range		74		

† Full range is -40°C to 125°C for I suffix.

input characteristics

PARAMETER		TEST CONDITIONS	T _A	MIN	TYP	MAX	UNIT
I _{IO}	Input offset current	V _{IC} = V _S /2, R _L = 100 kΩ, V _O = V _S /2, R _S = 50 Ω	≤25°C		1	60	pA
			≤70°C			100	
			≤125°C			1000	
I _{IB}	Input bias current		≤25°C		1	60	pA
			≤70°C			200	
			≤125°C			1000	
r _i (d)	Differential input resistance		25°C		1000		GΩ
C _{IC}	Common-mode input capacitance	f = 1 kHz	25°C		8		pF

power supply

PARAMETER	TEST CONDITIONS	T_A^\dagger	MIN	TYP	MAX	UNIT
I_Q Quiescent current (per channel)	$V_O = V_S/2$	25°C		7	11	μA
		Full range			16	
PSRR Power supply rejection ratio ($\Delta V_S/\Delta V_{IO}$)	$V_S = 2.7\text{ V to }16\text{ V}$, $V_{IC} = V_S/2\text{ V}$ No load,	25°C	74	82		dB
		Full range	70			

† Full range is -40°C to 125°C for I suffix.

TLV27L1 TLV27L2

SLOS378A – SEPTEMBER 2001 – REVISED JULY 2003

electrical characteristics at recommended operating conditions, $V_S = 2.7\text{ V}$, 5 V , and $\pm 5\text{ V}$ (unless otherwise noted) (continued)

output characteristics

PARAMETER	TEST CONDITIONS	T_A^\dagger	MIN	TYP	MAX	UNIT
V_O Output voltage swing from rail	$V_{IC} = V_S/2$, $I_{OL} = 100\text{ }\mu\text{A}$	$V_S = 2.7\text{ V}$	25°C	200	160	V
		Full range	220			
		$V_S = 5\text{ V}$	25°C	120	85	
		Full range	200			
		$V_S = \pm 5\text{ V}$	25°C	120	50	
		Full range	150			
	$V_{IC} = V_S/2$, $I_{OL} = 500\text{ }\mu\text{A}$	$V_S = 5\text{ V}$	25°C	800	420	
		Full range	900			
		$V_S = \pm 5\text{ V}$	25°C	400	200	
		Full range	500			
I_O Output current	$V_O = 0.5\text{ V}$ from rail	$V_S = 2.7\text{ V}$	25°C	400		μA

† Full range is -40°C to 125°C for I suffix.

dynamic performance

PARAMETER	TEST CONDITIONS	T_A	MIN	TYP	MAX	UNIT
GBP Gain bandwidth product	$R_L = 100\text{ k}\Omega$, $C_L = 10\text{ pF}$, $f = 1\text{ kHz}$	25°C		160		kHz
SR Slew rate at unity gain	$V_{O(pp)} = 1\text{ V}$, $R_L = 100\text{ k}\Omega$, $C_L = 50\text{ pF}$	25°C		0.06		$\text{V}/\mu\text{s}$
		-40°C		0.05		
		125°C		0.8		
ϕ_M Phase margin	$R_L = 100\text{ k}\Omega$, $C_L = 50\text{ pF}$	25°C		62		$^\circ$
t_S Settling time (0.1%)	$V_{(STEP)pp} = 1\text{ V}$, $A_V = -1$, $C_L = 50\text{ pF}$, $R_L = 100\text{ k}\Omega$	25°C	Rise	62		μs
			Fall	44		

noise/distortion performance

PARAMETER	TEST CONDITIONS	T_A	MIN	TYP	MAX	UNIT
V_n Equivalent input noise voltage	$f = 1\text{ kHz}$	25°C		89		$\text{nV}/\sqrt{\text{Hz}}$
I_n Equivalent input noise current	$f = 1\text{ kHz}$	25°C		0.6		$\text{fA}/\sqrt{\text{Hz}}$

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V _{IO}	Input offset voltage	vs Common-mode input voltage	1, 2, 3
I _{IB} /I _{IO}	Input bias and offset current	vs Free-air temperature	4
V _{OH}	High-level output voltage	vs High-level output current	5, 7, 9
V _{OL}	Low-level output voltage	vs Low-level output current	6, 8, 10
I _Q	Quiescent current	vs Supply voltage	11
		vs Free-air temperature	12
Supply voltage and supply current ramp up			13
A _{VD}	Differential voltage gain and phase shift	vs Frequency	14
GBP	Gain-bandwidth product	vs Free-air temperature	15
ϕ _m	Phase margin	vs Load capacitance	16
CMRR	Common-mode rejection ratio	vs Frequency	17
PSRR	Power supply rejection ratio	vs Frequency	18
Input referred noise voltage		vs Frequency	19
SR	Slew rate	vs Free-air temperature	20
V _{O(PP)}	Peak-to-peak output voltage	vs Frequency	21
Inverting small-signal response			22
Inverting large-signal response			23
Crosstalk		vs Frequency	24

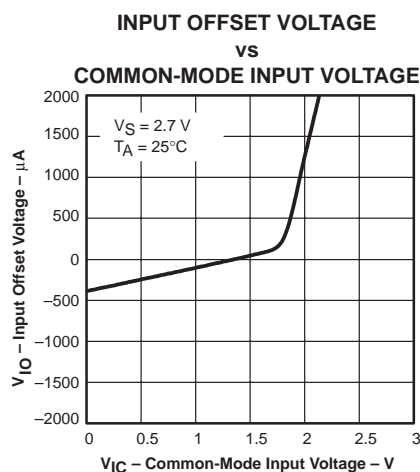


Figure 1

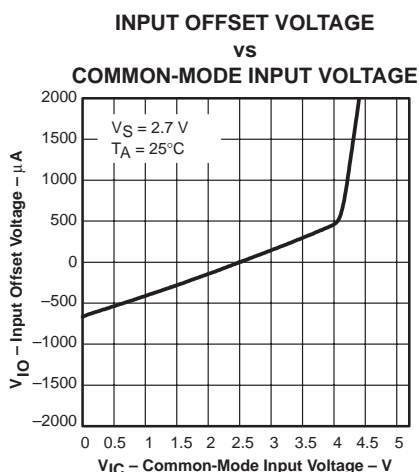


Figure 2

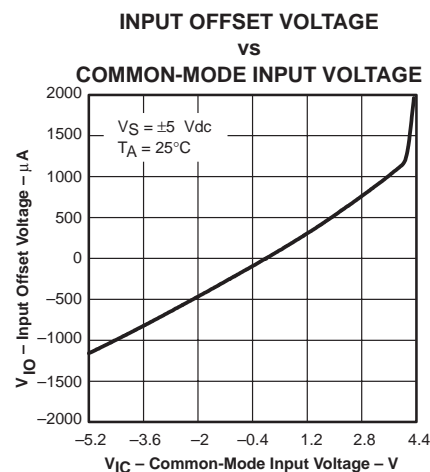


Figure 3

TYPICAL CHARACTERISTICS

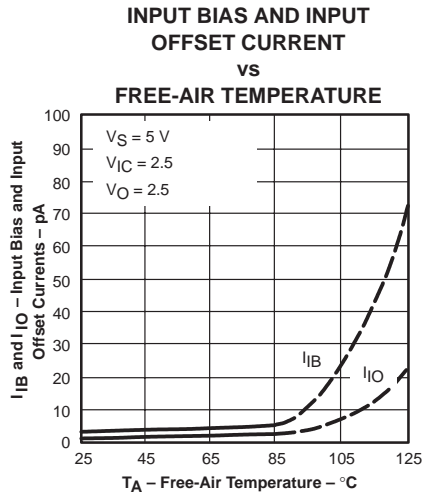


Figure 4

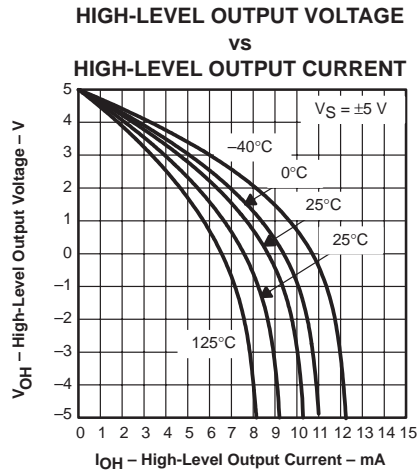


Figure 5

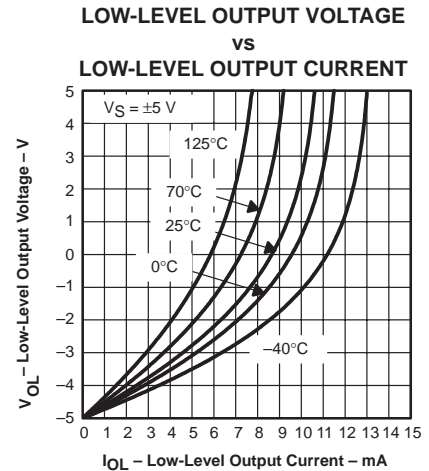


Figure 6

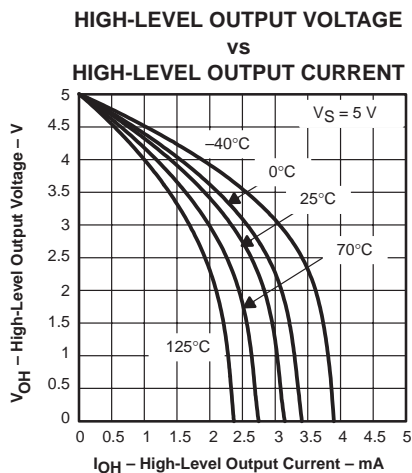


Figure 7

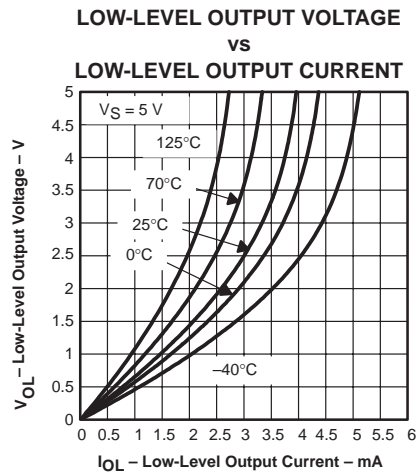


Figure 8

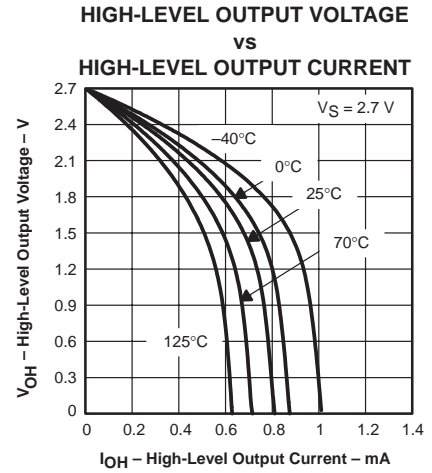


Figure 9

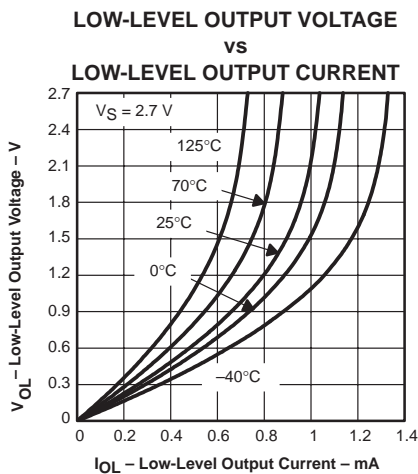


Figure 10

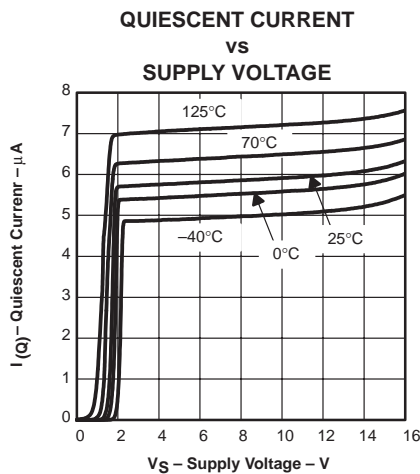


Figure 11

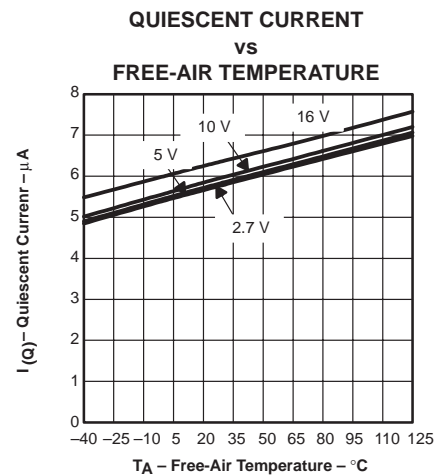


Figure 12

TYPICAL CHARACTERISTICS

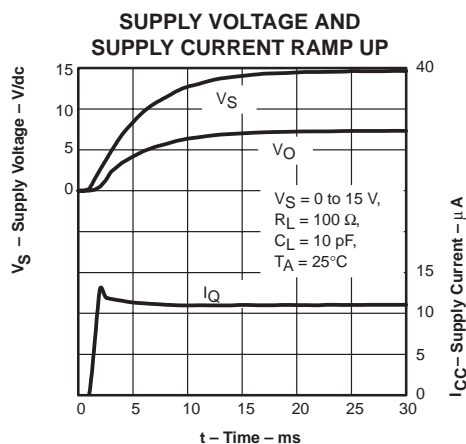


Figure 13

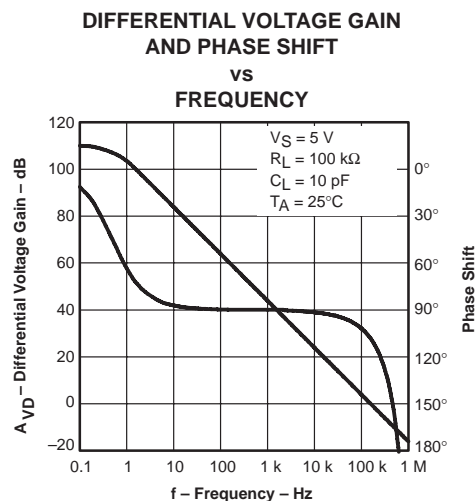


Figure 14

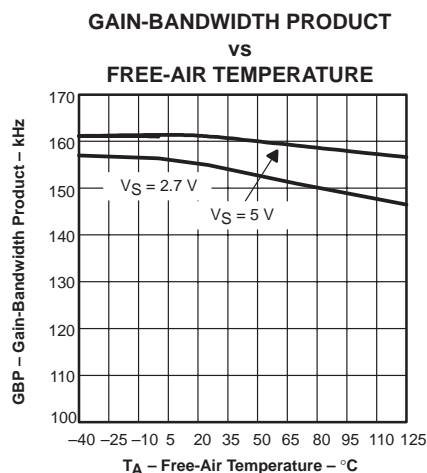


Figure 15

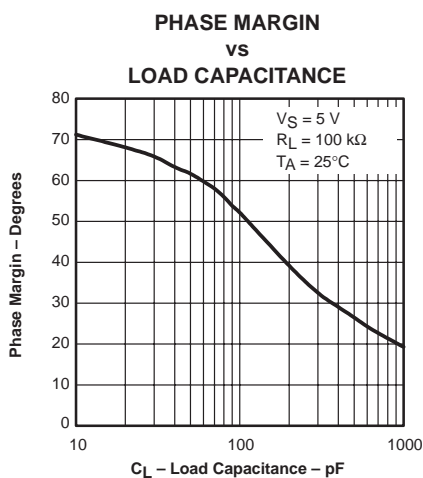


Figure 16

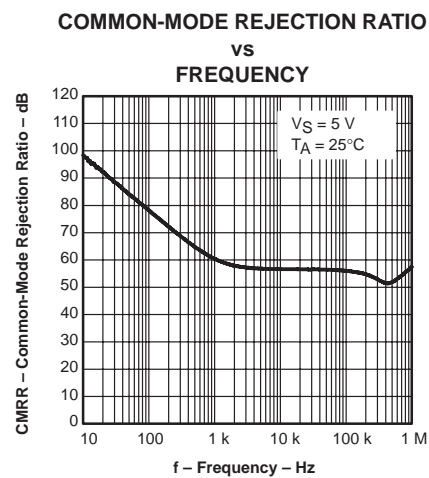


Figure 17

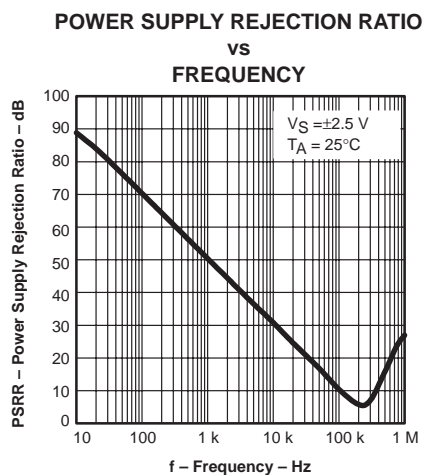


Figure 18

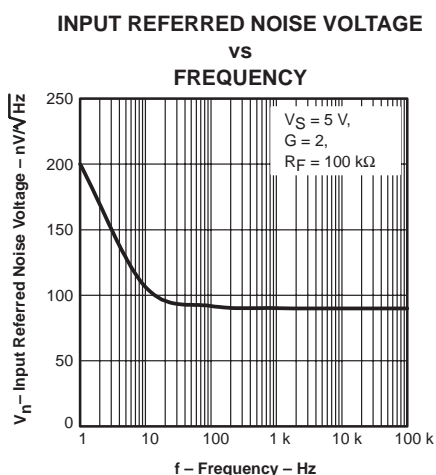


Figure 19

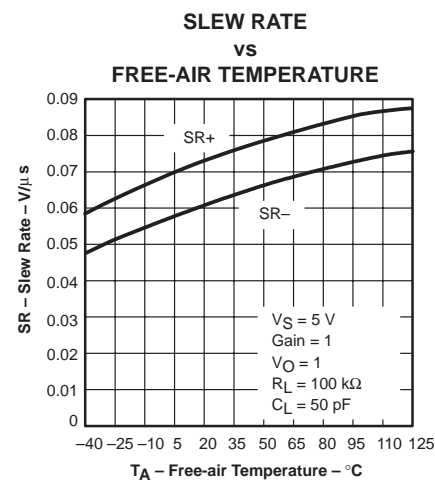
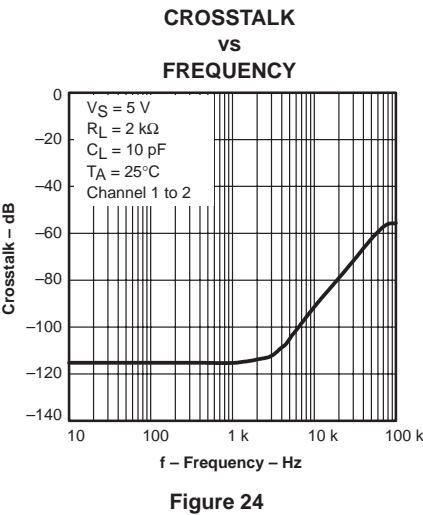
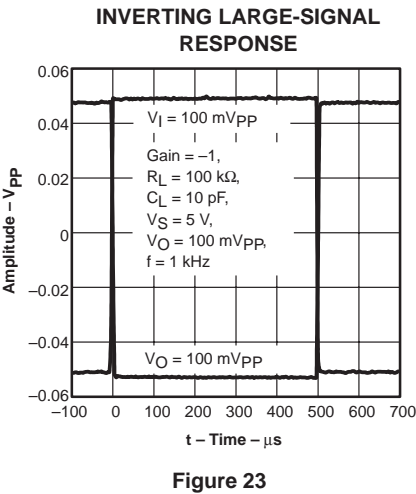
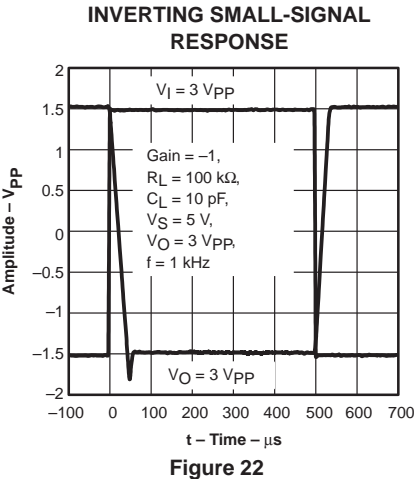
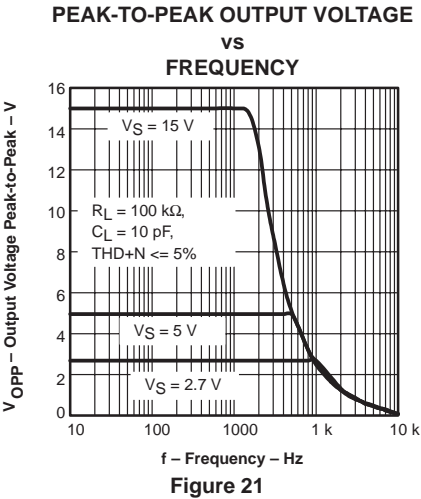


Figure 20

TYPICAL CHARACTERISTICS



APPLICATION INFORMATION

offset voltage

The output offset voltage (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:

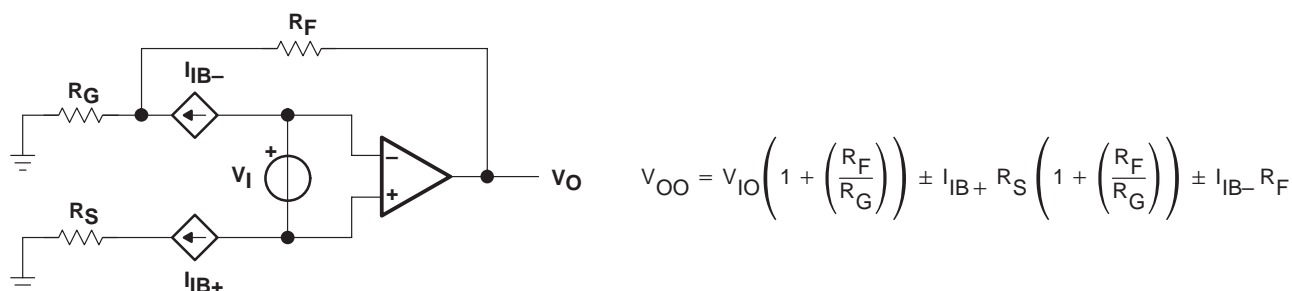


Figure 25. Output Offset Voltage Model

general configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 26).

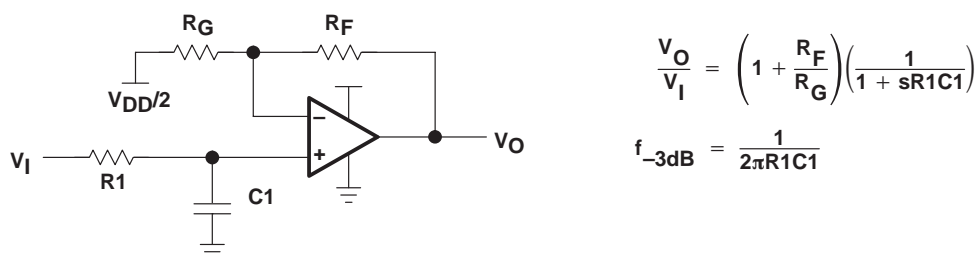


Figure 26. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

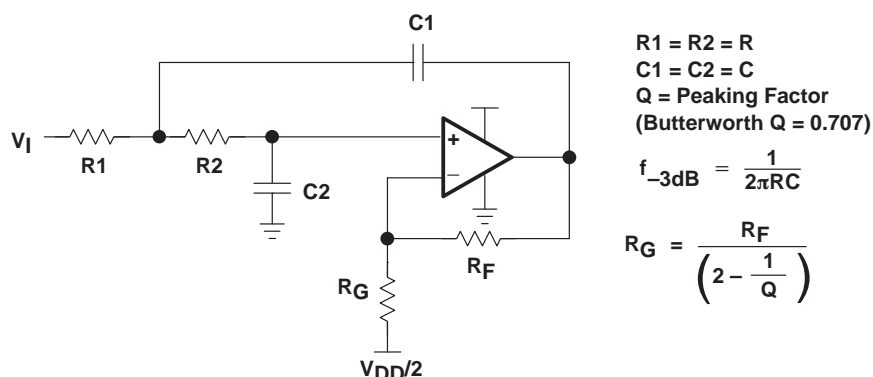


Figure 27. 2-Pole Low-Pass Sallen-Key Filter

APPLICATION INFORMATION

circuit layout considerations

To achieve the levels of high performance of the TLV27Lx, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

- Ground planes—It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling—Use a 6.8- μ F tantalum capacitor in parallel with a 0.1- μ F ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1- μ F ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1- μ F capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets—Sockets can be used but are not recommended. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- Short trace runs/compact part placements—Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components—Using surface-mount passive components is recommended for high performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

APPLICATION INFORMATION

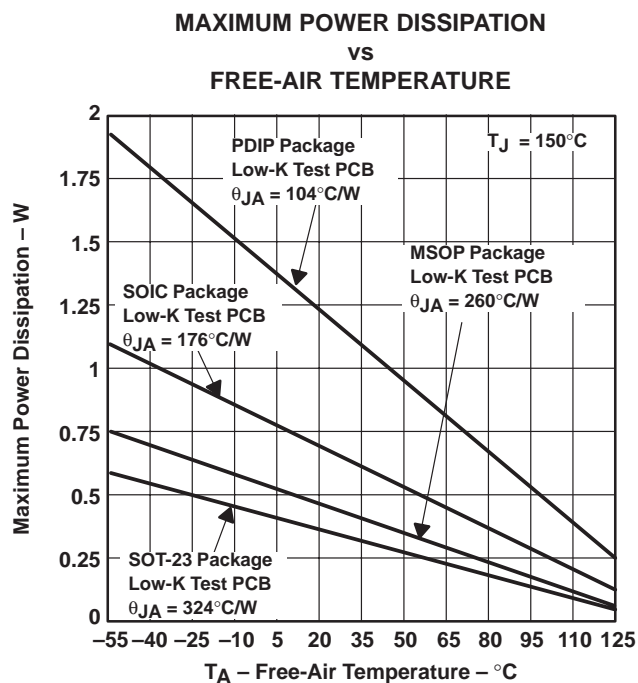
general power dissipation considerations

For a given θ_{JA} , the maximum power dissipation is shown in Figure 28 and is calculated by the following formula:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right)$$

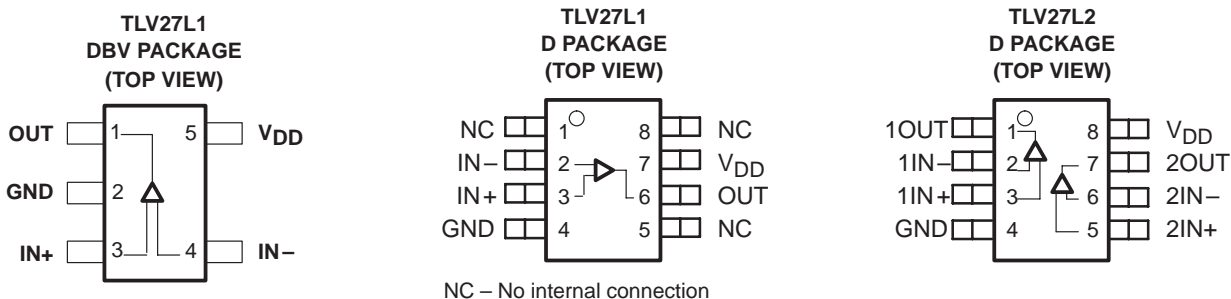
Where:

- P_D = Maximum power dissipation of TLV27Lx IC (watts)
- T_{MAX} = Absolute maximum junction temperature (150°C)
- T_A = Free-ambient air temperature (°C)
- $\theta_{JA} = \theta_{JC} + \theta_{CA}$
 - θ_{JC} = Thermal coefficient from junction to case
 - θ_{CA} = Thermal coefficient from case to ambient air (°C/W)



NOTE A: Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 28. Maximum Power Dissipation vs Free-Air Temperature



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products

Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DSP	dsp.ti.com
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com

Applications

Audio	www.ti.com/audio
Automotive	www.ti.com/automotive
Broadband	www.ti.com/broadband
Digital Control	www.ti.com/digitalcontrol
Military	www.ti.com/military
Optical Networking	www.ti.com/opticalnetwork
Security	www.ti.com/security
Telephony	www.ti.com/telephony
Video & Imaging	www.ti.com/video
Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments
Post Office Box 655303 Dallas, Texas 75265